

Product data sheet

1. General description

Planar passivated four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in general purpose bidirectional switching and phase control applications. This sensitive gate "series E" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- · Direct triggering from low power drivers and logic ICs
- · High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate for easy logic level triggering
- Triggering in all four quadrants

3. Applications

- General purpose motor controls
- General purpose switching

4. Quick reference data

able 1. Q	uick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage			-	-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 110 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>		-	-	4	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>		-	-	35	A
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics		· · ·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>		-	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>		-	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>		-	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _I = 25 °C; <u>Fig. 7</u>		-	-	25	mA

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	
2	T2	main terminal 2	Ì ↓ ↓ ↓	N
3	G	gate		
mb	T2	mounting base; main terminal 2		sym051

6. Ordering information

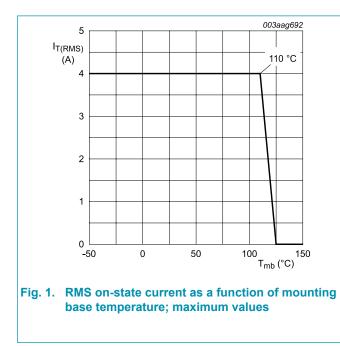
Table 3. Ordering information					
Type number Package					
	Name	Description	Version		
BTA234-600E	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78		

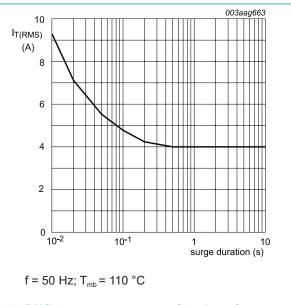
7. Limiting values

Table 4. Limiting values

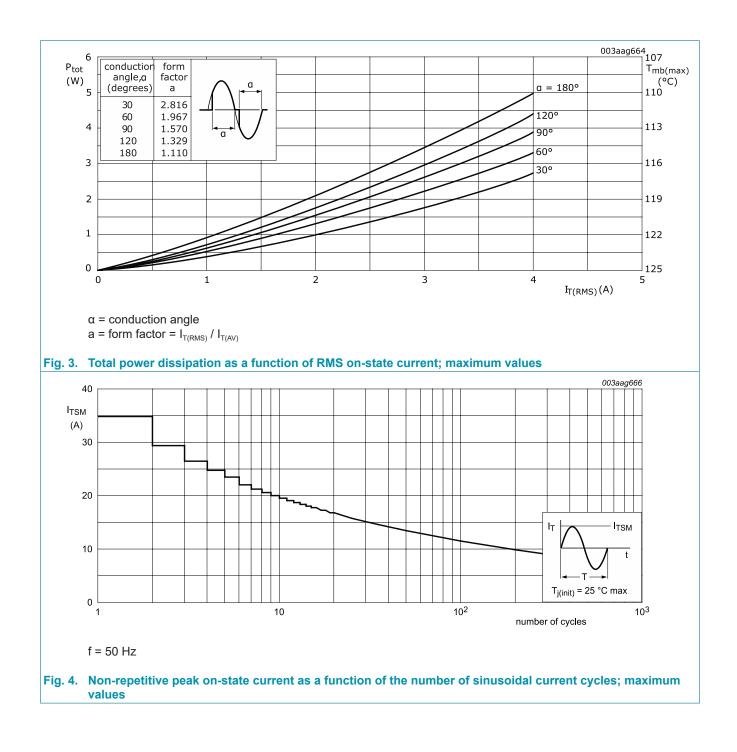
In accordance with the Absolute Maximum Rating System (IEC 60134).

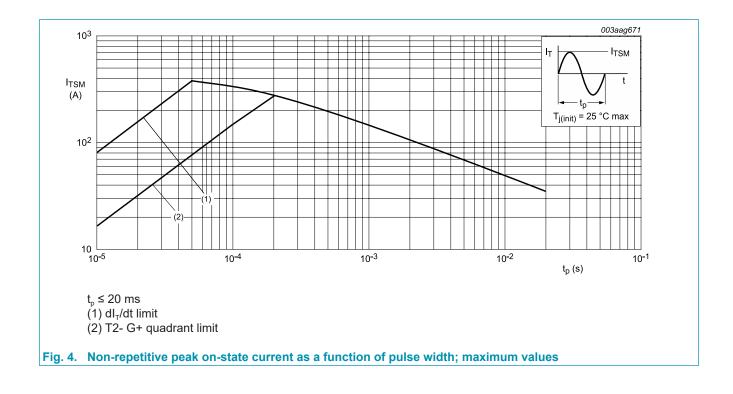
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	600	V
$I_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; T _{mb} ≤ 110 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	4	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig 4; Fig 5</u>	-	35	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	-	38.5	A
l ² t	l ² t for fusing	t_p = 10 ms; sine-wave pulse	-	6.1	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 20 mA; T2+ G+	-	50	A/µs
		I _G = 20 mA; T2+ G-	-	50	A/µs
		I _G = 20 mA; T2- G-	-	50	A/µs
		I _G = 50 mA; T2- G+	-	10	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	125	°C





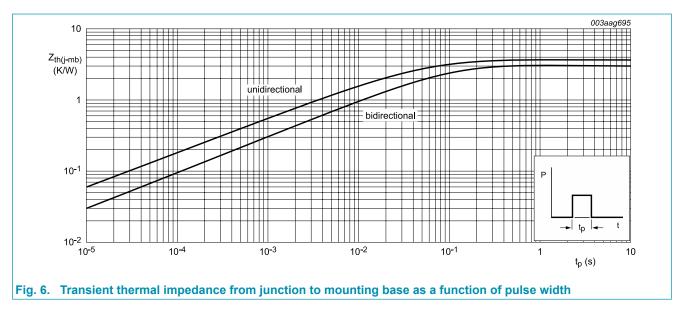






8. Thermal characteristics

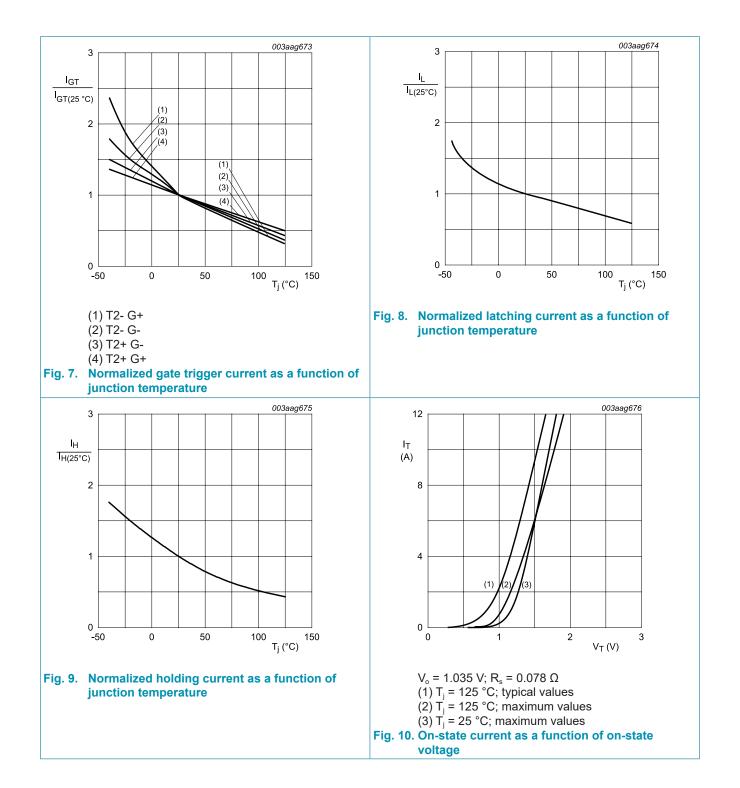
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	full cycle; <u>Fig. 6</u>	-	-	3.7	K/W
		half cycle; <u>Fig. 6</u>	-	-	3	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W



9. Characteristics

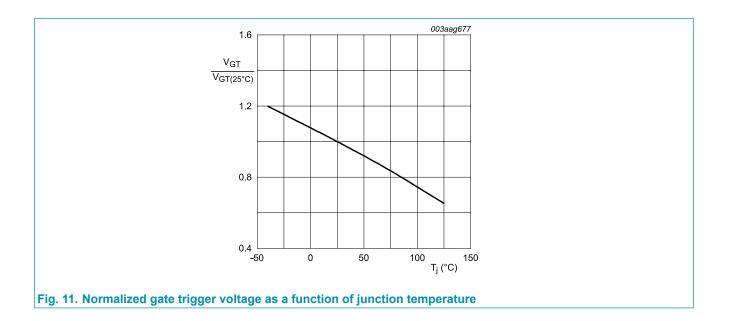
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics		l.			_
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7	-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7	-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 7	-	-	25	mA
l	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 8	-	-	15	mA
		V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	25	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	15	mA
		V _D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; Fig. 8	-	-	15	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	15	mA
V _T	on-state voltage	I _T = 6 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.5	V
V _{gt}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A;T _j = 25 °C; <u>Fig. 11</u>	-	0.7	1	V
		V _D = 400V; I _T = 0.1 A;T _j = 25 °C; <u>Fig. 11</u>	0.25	0.4	-	V
I _D	off-state current	$V_{\rm D}$ = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	1	I			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	80	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ Tj} = 125 \text{ C};$ $dI_{com}/dt = 1.8 \text{ A/ms}; \text{ gate open circuit}$	15	-	-	A/ms
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ Tj} = 125 \text{ C}; \text{ I}_{T(RMS)} = 4 \text{ A}; $ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	1.5	-	-	A/ms
t _{gt}	gate-controlled turn-on time	$I_{TM} = 6 \text{ A}; V_D = 400 \text{ V}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	2	-	μs
						-

BT234-600E 4Q Triac

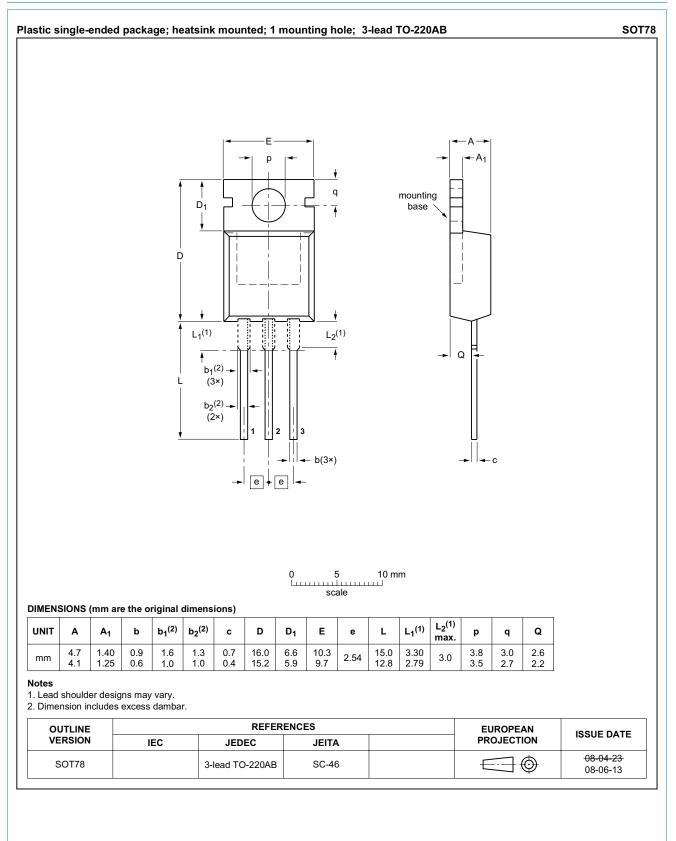


4Q Triac

BT234-600E



10. Package outline



11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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